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High-purity C₃N quantum dots for enhancing fluorescence detection of metal ions†

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A new type of two-dimensional layered material, namely C₃N, has been fabricated by polymerization and recommended to have great potential in various applications such as the development of electronic devices or photo-detectors, due to its enhanced conductivity, electronegativity, and unique optical properties. Actually, most of the present research on C₃N is limited in the scope of theoretical calculation, while experimental research is blocked by inefficient synthesis with low purity and homogeneity. Here, we report an optimized efficient synthesis method of high-purity C₃N QDs in aqueous solution by polymerization of DAP with combined centrifugation and filtration of products, with the synthesis yield up to $33.1 \pm 3.1\%$. Subsequently, the C₃N QDs have been used as novel metal ion probes exhibiting a sensitive fluorescent response to various metal ions including monovalent alkaline metals (Li⁺, Na⁺, and K⁺), divalent alkaline-earth metals (Mg²⁺, Ca²⁺, and Sr²⁺), and multivalent transition metals (Cu²⁺, Co²⁺, Ni²⁺, and Au³⁺, Fe³⁺, Cr³⁺) due to the high electronegativity of the C₃N surface. Particularly, the fluorescent quenching response of Al³⁺, Ga³⁺, In³⁺, and Sc³⁺ ions is significantly different from the fluorescent enhanced response of most other carbon-based QDs, which is promising for enriching the detection methods of these metal ions and beneficial to improve the accuracy of ion recognition.

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1. Introduction

Due to their unique physical and chemical properties, two dimensional (2D) graphene-based materials have attracted sustained and widespread interest in fundamental and applied research, including sensors,^{1,2} ion sieving,^{3,4} catalysis,⁵ and electronic devices.⁶ To enrich the electrical properties of graphene for various applications, doping or modification methods are commonly used,^{7–9} such as regulating the bandgap of graphene,¹⁰ improving the conductivity of graphene oxide,^{11,12} or improving the thermal conductivity of reduced graphene oxide.¹³ Particularly, in optics, graphene quantum dots (GQD) gained a lot of attention due to their tunable bandgap for fluorescence properties, excellent photostability, good biocompatibility and low toxicity, with wide applications in drug delivery, bioimaging and biosensing.^{14,15} Element doping is the most common pathway used to regulate the PL intensity and wavelength of GQDs to further improve the optical

performance.^{16,17} Among the numerous candidates as dopants, for example nitrogen (N), sulfur (S), boron (B), and phosphorus (P), nitrogen (N) owns the advantages of having a comparable atomic size to carbon (C) atoms, strong bond formation induced by its five valence electrons, and potentially strong electronegativity.^{18,19}

However, there exists significant instability in performance obtained by extremely high doping, as these methods often rely on a large number of defects or molecular adsorption on graphene, resulting in uneven distribution of dopants and unstable structures, *i.e.*, it is challenging to obtain 2D graphene-based materials such as N-doped GQDs with excellent performance as well as a stable structure through high doping. Therefore, some scientists have turned their attention to bottom-up synthesis of 2D Carbon-nitrogen (C_xN_y) materials (including carbon-nitrogen QDs) directly with periodic distributions of elements and stable lattice structure.

2D Carbon-nitrogen materials, with a structure similar to graphene and a high nitrogen content, such as g-C₃N₄,²⁰ C₃N₅,²¹ C₃N₃,^{22,23} C₁N₁,²⁴ C₂N,²⁵ and C₃N,^{26,27} have recently gained widespread attention in theoretical and experimental research. Especially, compared to graphene, with enhanced electrical conductivity, electronegativity, and good biocompatibility. While, C₃N, as an emerging star among 2D C_xN_y materials, possesses great potential in electrical,^{27,28} optoelectronics,²⁹ and medical fields,³⁰ benefiting from its exceptionally stable structure based on an orderly distribution of covalently bound

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nitrogen atoms.³¹ Recently, Yang *et al.*²⁷ have utilized a conventional hydrothermal method to synthesize the C₃N QDs with a relatively long lifetime, and tuned the PL of C₃N QDs over the entire visible range (400–660 nm) up to the IR region based on the size dependence of the bandgap. Pei *et al.*³² have found that the emission energy of C₃N QDs can be doubly modulated by size and edge effects through an artificial neural network (ANN) combined with statistical learning. They have established the relationship between geometrical/electronic structures of ground states and emission wavelength for C₃N QDs, and provided a general approach to atomically precise design the full-color fluorescent carbon-based QDs with targeted functions and high performance. Actually, C₃N QDs are considered suitable for use in photodetectors to improve the response time, sensitivity and wavelength range of detection, not only because of the potentially excellent optical properties, such as the strong light absorption efficiency, the wide spectral range to IR, but also the contributions to increasing the lifetime of photo-generated carriers and transfer efficiency.^{28,29,33} Besides, benefiting from the higher bio-compatibility and degradability of C₃N QDs, the applications as biosensors or pharmaceuticals have been reported, for example, in the detection of xanthine and alpha-fetoprotein (one kind of tumor markers) by the localized surface plasmon resonance (LSPR) effect,^{34,35} and the inhibition of the aggregation of A β peptides against Alzheimer's disease (AD) by the specific π - π stacking and hydrogen bonding interactions.³⁰

Unfortunately, limited by the lack of efficient strategies to synthesize C₃N or C₃N QDs with high purity and homogeneity, most of the related research works stay at the theoretical level.^{36–40} Therefore, it is of great importance to overcome the shortages of existing synthesis methods to efficiently acquire C₃N or C₃N QDs with advanced performance, especially for the development of experimental studies and application promotions of C₃N.

Here, we report an efficient synthesis of C₃N quantum dots (QDs) with high purity and homogeneity through optimized solvothermal treatment of 2,3-diaminophenazine (DAP). The yield can reach up to 33.1 \pm 3.1%, and the lateral size of the obtained single- or bi-layered C₃N QDs ranges from 10 to 25 nm, with the central value at 20 nm. The lattice configuration and the elemental ratio of C₃N were confirmed by transmission electron microscopy (TEM) and X-ray photoelectron spectroscopy (XPS), respectively. Then, these obtained C₃N QDs have been used as the metal ion probe for the first time. Remarkably, the high-purity C₃N QDs exhibit a sensitive fluorescent response to various metal ions, including monovalent alkaline metals, divalent alkaline-earth metals, and multivalent transition metals, especially for fluorescence detection of Al³⁺, Ga³⁺, In³⁺, and Sc³⁺ ions, which cannot be achieved by traditional graphene QDs (GQDs). We attribute the excellent performance to the high electronegativity of the C₃N surface, which arises from the numerous N sites,^{28–30} greatly enhancing the adsorption of metal ions. Thus, our findings represent a facile step towards efficient synthesis of C₃N QDs with high purity and homogeneity for various applications.

2. Materials and methods

2.1 Materials

2,3-Diaminophenazine (DAP, 91.56 \pm 2.0%) was purchased from Stanford Analytical Chemicals Inc. Organic nylon filter membranes (Φ 50 mm, 0.1 μ m porus) were purchased from Haining Delv New Material Technology Co., Ltd. The ultrafiltration tube (15 mL, 1 kDa, 7500 \times g) was purchased from Pall Corporation. All chemical reagents of analytical grade including LiCl, NaCl, KCl, MgCl₂·6H₂O, CaCl₂, SrCl₂, CuCl₂·2H₂O, NiCl₂·6H₂O, CoCl₂·6H₂O, CrCl₃, FeCl₃·6H₂O, AuCl₃, AlCl₃, ScCl₃, GaCl₃ and InCl₃ were obtained from Shanghai Aladdin Biochemical Technology Co., Ltd. (China). Various salt solutions were prepared from deionized water with an electrical resistivity of 18.2 M Ω cm.

2.2 Preparation of C₃N quantum dots (QDs)

The C₃N suspensions were prepared by a facile solvothermal method²¹ based on which the purification methods for both raw materials and products were optimized. Specifically, the DAP powder (19.0 mg) was first dissolved in 90.0 mL deionized water by grinding and ultrasonic pulverization. DAP aqueous solution was left to settle for 2 h, and then about 85.0 mL of DAP supernatant (\sim 0.45 mM) was transferred to a reactor and heated at 518 K for 89 hours. Until the reaction was over, centrifuged the suspension of products at 20 000 rpm for 1 h to remove impurities, followed by filtering the supernatant using 0.1 μ m organic nylon filter membranes and 1 kDa ultrafiltration tube. C₃N QDs solution with a concentration of 0.036 mg mL⁻¹ was obtained, and the synthesis rate was up to 33.1 \pm 3.1% (see eqn (S1)†).

2.3 Characterization methods

Atomic force microscope (AFM, Cypher S, Oxford Instruments Oxford Instruments Technology (Shanghai) Co., England) was used to determine the height and particle diameter of C₃N QDs. AFM images were obtained under the mode of AC Air Topography using a silicon tip coated with gold at a force constant of 3.10–37.60 N m⁻¹. The morphology, particle size, and lattice configuration of C₃N QDs were carried out on transmission electron microscopy (TEM, Talos F200C, Thermo Fisher Scientific, America). The size distribution was further confirmed by nano-particle size analyzer (BeNano 180 Zeta Pro, Dandong Baxter Instrument Co., China) with detection angle of 173°. Chemical element content X-ray photoelectron spectra (XPS, K-Alpha, Thermo Fisher Scientific, America) with an excitation source of Al K α rays ($h\nu$ = 1486.60 eV) was used to quantify the elemental contents of C₃N QDs. Ultraviolet-visible (UV-vis) spectra were obtained by a UV-vis/NIR spectrophotometer (UH4150, Hitachi High-Tech Science Corporation, Japan) in the wavelength range of 200–800 nm. The photograph of C₃N QDs under ultraviolet (UV) light (wavelength 365 nm) was taken with illumination by a UV analyzer (ZF-7N, Shanghai Jiapeng Technology Co., Ltd, China). All fluorescence spectra (FL) were obtained by a fluorescence spectrophotometer (F-4600, Hong Kong Tian mei Co., Ltd, China) with all slit widths of 0.5 nm.



The fluorescence lifetime was obtained with a fluorescence lifetime spectrometer (FL3-111, Horiba, French). Fourier transform infrared (FTIR) spectra were measured using a Cary 600 Series FTIR Spectrometer (Micro-FTIR, Cary 660 + 620, Agilent Technologies Inc., America). The spectral range of FTIR was 650–4000 cm^{-1} .

2.4 Fluorescence sensitivity to metal ions of C_3N QDs

The chloride salt solution of different ions and concentrations (such as Al^{3+} , Sc^{3+} , Ga^{3+} and In^{3+} (20, 60, 120, 200, 600 and 1200 mM); Li^+ , Na^+ , K^+ , Mg^{2+} , Ca^{2+} , Sr^{2+} , Cu^{2+} , Ni^{2+} , Co^{2+} (120, 200 and 1200 mM); Au^{3+} , Fe^{3+} and Cr^{3+} (2, 6 and 12 mM)) were prepared in advance. Mixed 6 mL salt solution and 6 mL of a C_3N QD solution (0.012 mg mL^{-1}), and then obtained the spectra using a fluorescence spectrophotometer (the concentration of C_3N QD in mixed solutions is 0.006 mg mL^{-1}). The relative fluorescence ratio ($F - F_0/F_0$) was used to evaluate the fluorescence quenching efficiency as the previous works,^{41,42} where F and F_0 represent the PL intensity of the C_3N QDs solution with or without (w/o) metal ions added, respectively. Each PL intensity value used here is the average of the area integrals from 394 to 750 nm of three independent experiments, and the error bar is equal to the statistical deviation. The raw data and calculating values in Fig. 3 and 4 can be found in Fig. S6 and Table S2, and Fig. S7 and Table S4,[†] respectively.

3. Results and discussion

3.1 Characterization of C_3N QDs

The surface morphology and lateral size distribution of the C_3N QDs were characterized by TEM and AFM. The C_3N QDs have an average lattice constant of 0.26 ± 0.01 nm (Fig. 1b and S1[†]), and a thickness of approximately 0.6 nm or 1.2 nm (Fig. 1c), consistent with the structure sizes of C_3N reported before.^{27–30} The histograms of the lateral size for C_3N QDs were calculated by TEM (more than 250 points) and AFM (more than 750 points) images, with an average value of 20 ± 10 nm. The size distribution was further confirmed by nanoparticle size analyzer (see Fig. S2[†]), with sizes ranging from 13 nm to 33 nm and an average size of approximately 21 nm.

XPS survey spectra show that the C_3N QDs mainly composed of C (284.80 eV),^{43,44} N (399.10 eV),^{45,46} and O (532.30 eV)⁴⁷ elements. The ratio of C to N were ~ 3.1 and ~ 3.6 for C_3N QDs and DAP, respectively (Fig. 1d). Although the content of N (20.2%) in C_3N was close to that of DAP (21.1%) (see Table S1[†]), the nitrogenous compositions present significant differences, as shown in N 1s spectra of Fig. 1e. N 1s spectrum of C_3N was only composed of graphitic-N (401.80 eV) and $-\text{NH}_2$ (399.80 eV),^{48–50} whereas DAP was primarily composed of $-\text{NH}_2$ and pyridinic-N (398.7 eV).^{48,49,51,52} Such different compositions of nitrogenous groups were also observed in Fourier transform infrared spectra (FTIR) (see Fig. S4[†]). It suggests an efficient synthesis of high purity C_3N from DAP based on the almost full reaction from pyridinic-N to graphitic-N.

We systematically investigated the optical properties of the high purity C_3N QDs. As shown in the inset of Fig. 2a, the

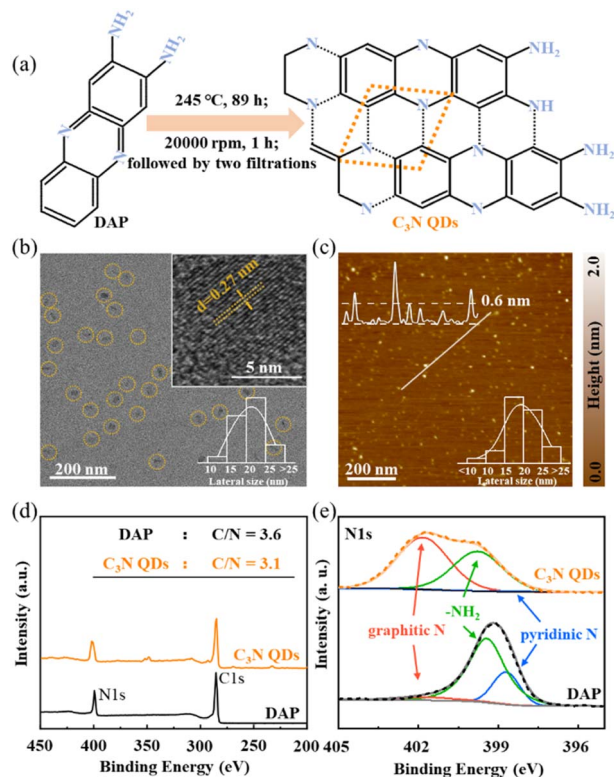


Fig. 1 Synthesis of C_3N QDs with high purity and homogeneity through optimized solvothermal treatment of 2,3-diaminophenazine (DAP). (a) Synthetic routes and purification methods. (b) TEM images of C_3N QDs and the insets correspond to the HRTEM patterns of C_3N QDs. (c) AFM image of C_3N QDs. (d) XPS survey spectra of DAP (black) and C_3N QDs (orange). (e) N 1s spectra of DAP and C_3N QDs.

aqueous solution of C_3N QDs is yellowish in natural light and bright blue upon 365 nm UV lights. The UV-visible absorption spectrum (Abs. in Fig. 2a) exhibits four pronounced absorption peaks at about 206, 255, 365, and 418 nm with an optical absorption edge at ~ 450 nm, where, two peaks at 255 and 365 nm (black dotted lines in Fig. 2a) are particularly pronounced. The corresponding adsorption peaks are assigned to the $n-\sigma^*$ transition of C–NH, the $\pi-\pi^*$ transition associated with C=C and C=N, the $n-\pi^*$ transition of the C=O and C=N,^{50,53,54} and the electron transition of the conjugated structure between the phenazine ring structure and $-\text{NH}_2$.⁵⁵ The

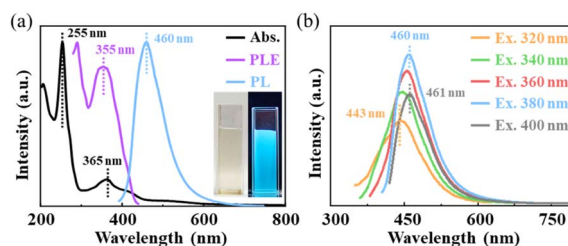


Fig. 2 Optical spectra of C_3N QDs. (a) UV-visible absorption (Abs.), excitation (PLE, detected at 460 nm) and PL spectra (excites at 380 nm). (b) PL spectra excited from 320 to 400 nm. The dotted lines and colourful labels indicate the peak positions of each spectrum.



excitation peak of PLE at 355 nm (in Fig. 2a, purple line) almost agrees with the corresponding absorption peaks at 365 nm, suggesting that the emission can be characterized by the decay of band-edge exciton-state rather than defect-state. We further tested the fluorescence spectra (PL) of C_3N QDs in same concentration under excitation wavelength from 320 nm to 400 nm (Fig. 2b). The emission peaks gradually red shift from 443 nm to 461 nm with the increasing excitation wavelength, and such excitation-dependent behavior can be explained by a wide distribution of particle size of C_3N QDs. When the excitation wavelength is 380 nm, the emission peak has the highest intensity at 460 nm (light blue line in Fig. 2a and b). Besides, C_3N QDs have a relatively long lifetime of 5.47 ns (see Fig. S5†), compared to GQDs with a typical value of 0.1–1 ns.^{27,56,57}

3.2 Fluorescence quenching

We note that the traditional GQDs exhibit no fluorescence quenching response to group IIIA ions and rare-earth ions, such as Al^{3+} , Ga^{3+} , In^{3+} , and Sc^{3+} , but instead show fluorescence recovery or enhancement upon these ions^{58–61} due to their adsorption on oxygen-containing groups rather than π -conjugated regions.⁶² In a sense, there are certain limitations to detect the ions mentioned above using traditional fluorescent GQDs. Accordingly, the C_3N QDs reported in this work have unique performance for metal ions detection as a promising fluorescent probe. In experiments, 6 mL salt solution containing a variety of single component metal ions with concentrations from 20 to 1200 mM was added to 6 mL of a C_3N QD solution (0.012 mg mL^{-1}), and the PL spectra were measured using a fluorescence spectrophotometer excited at 380 nm. The fluorescence quenching efficiency was evaluated as the relative fluorescence ratio $((F - F_0)/F_0)$, where F_0 and F represent the PL intensity of the C_3N QDs before and after incubation with different metal ions, respectively. As shown in Fig. 3a, the relative fluorescence ratios of mixed solutions (0.006 mg mL^{-1} C_3N QDs upon different metal ions) exhibited a linear correlation with the logarithm of the concentrations of Al^{3+} , Ga^{3+} , In^{3+} , and Sc^{3+} ions in the range of 10–100 mM (the inset in Fig. 3a). In

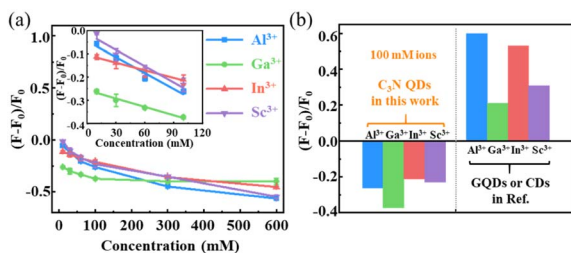


Fig. 3 Relative fluorescence ratios of C_3N QDs. (a) Dependence of PL intensity of C_3N QDs on gradient concentrations of Al^{3+} , Ga^{3+} , In^{3+} , and Sc^{3+} ions. (b) Comparison of the relative fluorescence ratios of C_3N QDs and GQDs/CDs upon Al^{3+} , Ga^{3+} , In^{3+} , and Sc^{3+} ions (in ref. 58–61, see Table S3†). The concentration of C_3N QDs used here was 0.006 mg mL^{-1} . The blank samples contained deionized water and corresponding concentrations of metal ions in each of the experimental groups. The error bars are the statistical standard deviations, seeing ESI Table S2† for exact values.

Fig. 3a, the fluorescence quenching efficiency is at least 43% upon 600 mM metal ions. These results demonstrated a high sensitivity of C_3N QDs to Al^{3+} , Ga^{3+} , In^{3+} , and Sc^{3+} ions over a wide concentration range. The excellent performance may be attributed to the high electronegativity of the C_3N surface, originating from numerous N sites,^{38–40} which significantly enhances metal ion adsorption on N sites rather than oxygen groups, leading to charge transfer between the metal ions and C_3N surface.

The C_3N QDs also own a sensitive fluorescent response to other various metal ions, including monovalent alkaline metals (Li^+ , Na^+ , and K^+), divalent alkaline-earth metals (Mg^{2+} , Ca^{2+} , and Sr^{2+}), and multivalent transition metals (Cu^{2+} , Co^{2+} , Ni^{2+} , and Au^{3+} , Fe^{3+} , Cr^{3+}). Using the same fluorescence detection method described above, the C_3N QDs can also be quenched by alkaline metals (Li^+ , Na^+ , and K^+), divalent alkaline-earth metals (Mg^{2+} , Ca^{2+} , and Sr^{2+}), and divalent transition metals (Cu^{2+} , Co^{2+} , Ni^{2+}) with a concentration range of 60–600 mM (Fig. 4a–c). Notably, for the trivalent transition metals (Au^{3+} , Fe^{3+} , Cr^{3+}), even extremely low ion concentrations of 1–6 mM still caused significant fluorescence quenching. The fluorescent C_3N QDs have been quenched to 98.5%, 81.2%, and 28.7% by Au^{3+} , Fe^{3+} , and Cr^{3+} ions at 6 mM concentration, respectively. The raw data and calculating values used in Fig. 3 and 4 have been presented in the ESI (see Table S2 and Fig. S6, and Table S4 and Fig. S7†) as support.

Considering the magnitudes of the fluorescence response to metal ions, the interaction strengths between C_3N QDs and metal ions can be arranged as follows: trivalent heavy metal ions

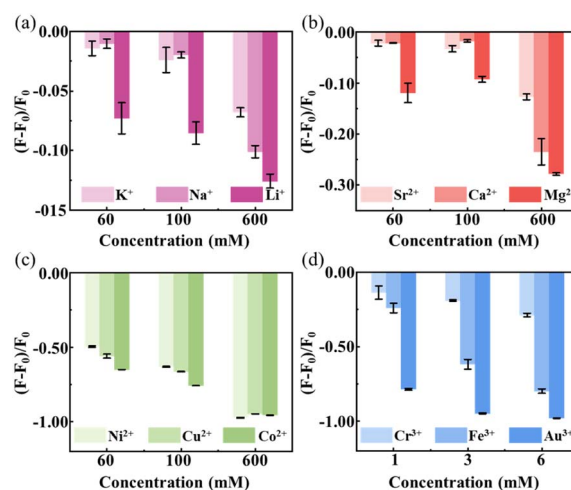


Fig. 4 Relative fluorescence ratios of C_3N QDs with various metal ions. (a) Relative fluorescence ratios after adding Li^+ , Na^+ , and K^+ ions at different concentrations. (b) Relative fluorescence ratios after adding Mg^{2+} , Ca^{2+} , and Sr^{2+} ions at different concentrations. (c) Relative fluorescence ratios after adding Cu^{2+} , Co^{2+} , and Ni^{2+} at different concentrations. (d) Relative fluorescence ratios after adding Au^{3+} , Fe^{3+} , and Cr^{3+} at different concentrations. F_0 and F represent the PL intensity before and after adding metal ions. The concentration of C_3N QDs used here was 0.006 mg mL^{-1} . The blank samples contained deionized water and corresponding concentrations of metal ions in each of the experimental groups. The error bars are the statistical standard deviation, seeing ESI Table S4† for exact values.



(Au³⁺, Fe³⁺, and Cr³⁺) > divalent heavy metal ions (Cu²⁺, Co²⁺, and Ni²⁺) > high-valence metal ions (Al³⁺, Ga³⁺, In³⁺, and Sc³⁺) > alkaline earth metal ions (Mg²⁺, Ca²⁺, and Sr²⁺) > alkaline metal ions (Li⁺, Na⁺, and K⁺). Based on these evidences, C₃N QDs reported here should be proposed as a promising fluorescent probe to monitor various metal ions due to their excellent performance in fluorescent responding properties.

4. Conclusions

In summary, an efficient synthesis of C₃N QDs with high purity and homogeneity from DAP molecules was realized by an optimized solvothermal method. Also benefiting from the optimizing purification methods in both pre-treatment of raw materials and further combined centrifugation and filtration of reaction products, the synthesis rate of C₃N QDs can reach up to 33.1 ± 3.1%, and the obtained C₃N QDs have a high purity. The TEM and AFM results combining with nanoparticle size analyzer revealed that an average lateral size of purified C₃N QDs is 20 ± 10 nm. The C₃N QDs have an average lattice constant of 0.26 ± 0.01 nm, and a thickness of single- or two-atomic layers. XPS results further demonstrated the efficient synthesis of C₃N from DAP based on the full reaction from pyridinic-N to graphitic-N.

Remarkably, the high-purity C₃N QDs exhibit a sensitive fluorescent response to various metal ions, especially quenched obviously by Al³⁺, Ga³⁺, In³⁺, and Sc³⁺ ions, which cannot be achieved by traditional GQDs. We speculate that the unconventional fluorescence quenching process of C₃N QDs arises from the cation-π interactions between the metallic ions and the π-conjugated system which promotes the ion-surface adsorption due to C₃N QDs with relatively high nitrogen content and orderly distribution of nitrogen. Moreover, the C₃N QDs also own a sensitive fluorescent response to other various metal ions. The interaction strengths between C₃N QDs and metal ions can be arranged as follows: trivalent heavy metal ions (Au³⁺, Fe³⁺, and Cr³⁺) > divalent heavy metal ions (Cu²⁺, Co²⁺, and Ni²⁺) > high-valence metal ions (Al³⁺, Ga³⁺, In³⁺, and Sc³⁺) > alkaline earth metal ions (Mg²⁺, Ca²⁺, and Sr²⁺) > alkaline metal ions (Li⁺, Na⁺, and K⁺).

In summary, our findings represent a significant step towards the high-efficiency synthesis of high-purity C₃N QDs, showing great potential in fluorescence detection for various metal ions. Actually, ion detections are the important applications of quantum dots, particularly, carbon-based quantum dots (CDs). Benefitting from the tunable bandgap for fluorescence property, excellent photostability, good biocompatibility and low toxicity of CDs. Whereas, C₃N QDs are considered to be one of the most potential materials because of their unique optical performances and interactions with ions coming from the relatively high nitrogen content and orderly distribution of nitrogen. Subject to the difficulty of synthesis and purification, no experimental work on ion detection of C₃N QDs has been reported before. Therefore, our work reported here can be considered as the first experimental verification on the application feasibility of C₃N QDs in ion detection. Additionally, the fact that the fluorescence responses of C₃N QDs to Al³⁺, Ga³⁺,

In³⁺, and Sc³⁺ ions are in the opposite performance compared with other CDs, provides a hopeful ion detection method with improved accuracy of ion recognition combined with other CDs.

Author contributions

P. L. and C. L. conceived the ideas. C. L., P. L., J. J. and H. Y. designed the experiments and co-wrote the manuscript. H. Y., C. H., P. L., C. L., and J. J. performed the experiments and prepared the data graphs. All authors discussed the results and commented on the manuscript.

Conflicts of interest

The authors declare no competing financial interests.

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